

HA2600, HA2605, HA2622, HA2602, HA2620, HA2625

High Impedance Operational Amplifiers

FEATURES

- Input Impedance — 500M Ω
- Offset Current — 1nA
- Bias Current — 1nA
- Gain Bandwidth Product — 100MHz
- High Gain — 150K
- Output Short Circuit Protection
- Meets MIL-STD-883

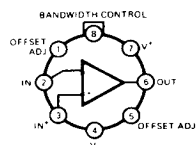
GENERAL DESCRIPTION

The 2600 series of high impedance operational amplifiers are monolithic integrated circuits fabricated using dielectric isolation. These internally compensated amplifiers feature excellent input parameters, low input bias and wide bandwidth. They are ideally suited for general purpose use in instrumentation and signal processing applications.

2600 through 2605 are compensated for unity gain. 2620 through 2625 are intended for closed loop gains of 5 or greater and feature increased slew rate and gain-bandwidth products.

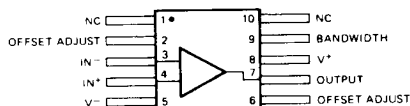
PIN CONFIGURATIONS, TOP VIEWS

(outline dwg TY)

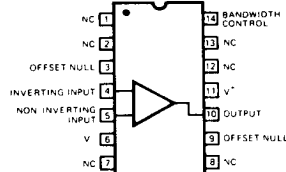


Pin 4 Connected to case

(outline dwg FB)



(outline dwg JD)



ORDERING INFORMATION

PART NUMBER	TEMPERATURE RANGE	PACKAGE TYPE	ORDER NUMBER
HA2600	-55°C to +125°C	TO-99	HA2-2600-2 *
		TO-91 Flat Pack	HA9-2600-2 *
		14 Pin CerDIP	HA1-2600-2 *
HA2602	-55°C to +125°C	TO-99	HA2-2602-2 *
		TO-91 Flat Pack	HA9-2602-2 *
		14 Pin CerDIP	HA1-2602-2 *
HA2605	0°C to +75°C	TO-99	HA2-2605-5
		TO-91 Flat Pack	HA9-2605-5
		14 Pin CerDIP	HA1-2605-5
HA2620	-55°C to +125°C	TO-99	HA2-2620-2 *
		TO-91 Flat Pack	HA9-2620-2 *
		14 Pin CerDIP	HA1-2620-2 *
HA2622	-55°C to +125°C	TO-99	HA2-2622-2 *
		TO-91 Flat Pack	HA9-2622-2 *
		14 Pin CerDIP	HA1-2622-2 *
HA2625	0°C to +75°C	TO-99	HA2-2625-5
		TO-91 Flat Pack	HA9-2625-5
		14 Pin CerDIP	HA1-2625-5

*883B processing is available for these devices. Order -8 instead of -2.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	$\pm 22.5\text{V}$
Input Voltage (Note 1)	$\pm 15\text{V}$
Differential Input Voltage	$\pm 12\text{V}$
Peak Output Current	Full Short Circuit Protection
Internal Power Dissipation (Note 2)	300mW
Lead Temperature (Soldering, 60 sec.)	$+300^{\circ}\text{C}$
Storage Temperature Range	-65°C to $+150^{\circ}\text{C}$
Operating Temperature Range	-55°C to $+125^{\circ}\text{C}$ (2600, 2602) 0°C to $+75^{\circ}\text{C}$ (2605)

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}\text{C}$, $V_S = \pm 15\text{V}$, unless otherwise specified)

PARAMETER	CONDITIONS	2600			2602			2605			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	$R_S \leq 10\text{k}\Omega$		0.5	4		3	5		3	5	mV
Input Offset Current			1	10		5	25		5	25	nA
Input Bias Current			1	10		5	25		5	25	nA
Input Resistance		100	500		40	300		40	300		$\text{M}\Omega$
Large Signal Voltage Gain	$R_L = 2\text{k}\Omega$, $V_O = \pm 10\text{V}$	100K	150K		80K	150K		80K	150K		V/V
Unity Gain Bandwidth	$V_O \leq 90\text{mV}$		12			12			12		MHz
Full Power Bandwidth	$R_L = 2\text{k}\Omega$, $C_L = 50\text{pF}$, $V_O = 20\text{V}_{\text{p-p}}$	50	75		50	75		50	75		KHz
Rise Time (Note 3)	$R_L = 2\text{k}\Omega$, $C_L = 100\text{pF}$		30	60		30	60		30	60	ns
Overshoot (Note 4)	$R_L = 2\text{k}\Omega$, $C_L = 100\text{pF}$		25	40		25	50		25	50	%
Slew Rate	$R_L = 2\text{k}\Omega$, $C_L = 100\text{pF}$, $V_O = \pm 5\text{V}$	4	7		4	7		4	7		V/ μs
Settling Time (to $\pm 10\text{mV}$ of Final Value)	$R_L = 2\text{k}\Omega$, $C_L = 100\text{pF}$, $V_O = \pm 5\text{V}$		1.5			1.5			1.5		ns
Output Current	$V_O = \pm 10\text{V}$	± 15	± 22		± 10	± 18		± 10	± 18		mA
Supply Current			3	3.7		3	4		3	4	mA

THE FOLLOWING SPECIFICATIONS APPLY FOR OPERATING TEMPERATURE RANGE

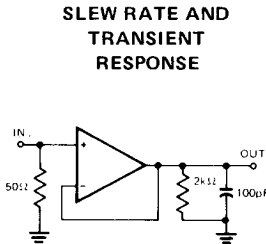
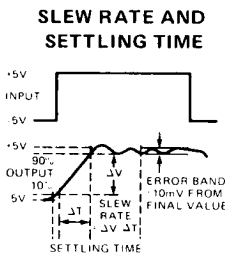
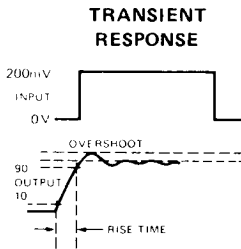
Input Offset Voltage	$R_S \leq 10\text{k}\Omega$		2	6			7			7	mV
Input Offset Current			5	30			60			40	nA
Input Bias Current			10	30			60			40	nA
Offset Voltage Average Drift	$R_S \leq 10\text{k}\Omega$		5								$\mu\text{V}/^{\circ}\text{C}$
Common Mode Rejection Ratio	$V_{\text{CM}} = \pm 5\text{V}$	80	100		74	100		74	100		dB
Common Mode Range		± 11			± 11			± 11			V
Supply Voltage Rejection Ratio	$V_S = \pm 9\text{V}$ To $\pm 15\text{V}$	80	90		74	90		74	90		dB
Large Signal Voltage Gain	$R_L = 2\text{k}\Omega$, $V_O = \pm 10\text{V}$	70k			60k			70k			V/V
Output Voltage Swing	$R_L = 2\text{k}\Omega$	± 10	± 12		± 10	± 12		± 10	± 12		V

NOTE 1: For supply voltages less than $\pm 15\text{V}$, the absolute maximum input voltage is equal to the supply voltage.

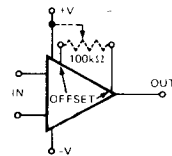
NOTE 2: Derate TO-91 at $4.5 \text{ mW}/^{\circ}\text{C}$ above 84°C ; derate TO-99 at $6.6 \text{ mW}/^{\circ}\text{C}$ above 105°C .

NOTE 3: $V_O = 400 \text{ mV}_{\text{p-p}}$

NOTE 4: $V_O = 800 \text{ mV}_{\text{p-p}}$



**SUGGESTED
OFFSET
ZERO ADJUST
HOOK-UP**



NOTE: MEASURED ON BOTH POSITIVE AND NEGATIVE TRANSITIONS.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	±22.5V
Input Voltage (Note 1)	±15V
Differential Input Voltage	±12V
Peak Output Current	Full Short Circuit Protection
Internal Power Dissipation (Note 2)	300mW
Lead Temperature (Soldering, 60 sec.)	300°C
Storage Temperature Range	-65°C to +150°C
Operating Temperature Range	-55°C to +125°C (2620, 2622) 0°C to +75°C (2625)

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, unless otherwise specified)

PARAMETER	CONDITIONS	2620			2622			2625			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage (Note 3)	$R_S \leq 10\text{k}\Omega$		0.5	4		3	5		3	5	mV
Input Offset Current			1	15		5	25		5	25	nA
Input Bias Current			1	15		5	25		5	25	nA
Input Resistance		65	500		40	300		40	300		M Ω
Large Signal Voltage Gain	$R_L = 2\text{k}\Omega$, $V_O = \pm 10\text{V}$, $C_L = 50\text{pF}$	100K	150K		80K	150K		80K	150K		V/V
Gain Bandwidth (Notes 4 and 5)	$R_L = 2\text{k}\Omega$, $C_L = 50\text{pF}$		100			100			100		MHz
Full Power Bandwidth	$R_L = 2\text{k}\Omega$, $C_L = 50\text{pF}$, $V_O = 20\text{V}_{\text{p-p}}$	400	600		320	600		320	600		KHz
Rise Time (Note 6)	$R_L = 2\text{k}\Omega$, $C_L = 50\text{pF}$		17	45		17	45		17	45	ns
Slew Rate (Note 6)	$R_L = 2\text{k}\Omega$, $C_L = 50\text{pF}$, $V_O = \pm 5.0\text{V}$	±25	±35		±20	±35		±20	±35		V/ μs
Output Current	$V_O = \pm 10\text{V}$	±15	±22		±10	±18		±10	±18		mA
Supply Current			3	3.7		3	4		3	4	mA

5

FOLLOWING SPECIFICATIONS APPLY FOR OPERATING TEMPERATURE RANGE

PARAMETER	CONDITIONS	2620			2622			2625			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	$R_S \leq 10\text{k}\Omega$			6			7			7	mV
Input Offset Current			5	35			60			40	nA
Input Bias Current			10	35			60			40	nA
Common Mode Rejection Ratio	$V_{\text{CM}} = \pm 5\text{V}$	80	100		74	100		74	100		dB
Common Mode Range		±11			±11			±11			V
Supply Voltage Rejection Ratio	$V_{\text{Supply}} = \pm 9\text{V}$ To $\pm 15\text{V}$	80	90		74	90		74	90		dB
Large Signal Voltage Gain	$R_L = 2\text{k}\Omega$, $V_O = \pm 10\text{V}$, $C_L = 50\text{pF}$	70k			60k			70k			V/V
Output Voltage Swing	$R_L = 2\text{k}\Omega$, $C_L = 50\text{pF}$	±10	±12		±10	±12		±10	±12		V

NOTE 1: For supply voltages less than $\pm 15\text{V}$, the absolute maximum input voltage is equal to the supply voltage.

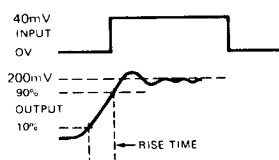
NOTE 2: Derate TO-91 at 4.5 mW/°C above 84°C; derate TO-99 at 6.6 mW/°C above 105°C.

NOTE 3: May be externally adjusted to zero.

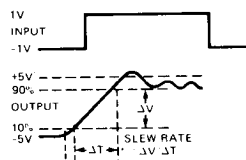
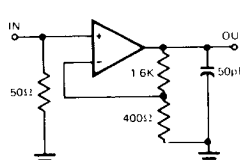
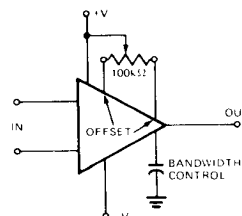
NOTE 4: $V_O < 90\text{mV}$.

NOTE 5: 40dB gain.

NOTE 6: $A_V = 5.0\text{V}$.

TRANSIENT
RESPONSE

SLEW RATE

SLEW RATE AND
TRANSIENT RESPONSESUGGESTED OFFSET
ZERO ADJUST AND
BANDWIDTH
CONTROL HOOK-UP

NOTE: MEASURED ON BOTH POSITIVE AND NEGATIVE TRANSITIONS.